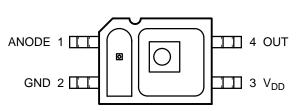


- **Converts Reflected Light Intensity to Output Voltage**
- Integral Color LEDs and Matching Color **Filters on Sensors**
- Sensor is a Monolithic Silicon IC **Containing a Photodiode, Operational** Amplifier, Feedback Components, and **Color Filter**
- **High-Output LEDs and High-Sensitivity** Sensors
- Single Voltage Supply Operation
- Surface-Mount Package

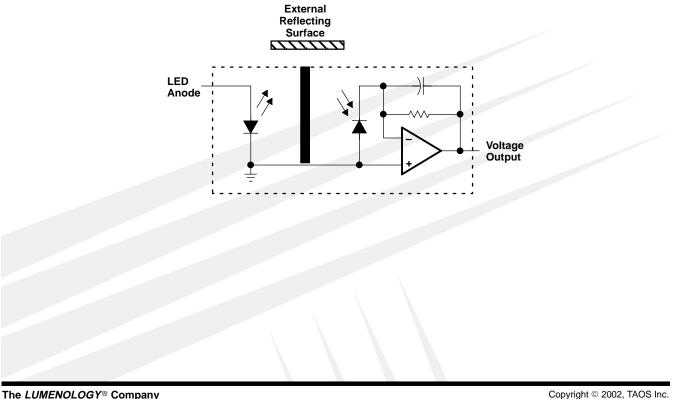
PACKAGE (TOP VIEW)



Description

The TRS1722, TRS1755, and TRS1766 are high-sensitivity reflective color sensors in red (630 nm), green (567 nm), and blue (470 nm) — respectively — with light-to-voltage converters. Each device consists of a colored LED light source, a photodiode light sensor with matching optical color filter, a transimpedance amplifier, and on-board signal conditioning. Output voltage is directly proportional to the reflected light intensity on the photodiode plus any ambient light (which may be considered noise).

Functional Block Diagram



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Terminal Functions

TERMINAL							
NAME	NO.	O. DESCRIPTION					
GND	2	Ground. LED cathode and sensor ground. All voltages are referenced to GND.					
ANODE	1	LED anode drive input					
OUT	4	Output voltage					
V _{DD}	3	Supply voltage					

Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{DD} (see Note 1)	
Duration of short-circuit current at (or below) 25°C	
LED DC forward current	
LED peak forward current (5% duty cycle @ 1 kHz or more)	100 mA
LED junction temperature, LED T _J	
Operating free-air temperature range, T _A	
Storage temperature range, T _{stg}	
Lead temperature in solder contact zone for 10 seconds	240°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

Recommended Operating Conditions

	MIN	MAX	UNIT
Supply voltage, V _{DD}	3	5.5	V
LED forward current	0	10	mA
Operating free-air temperature, T _A	0	70	°C

LED

PARAMETER		TEAT CONDITIONS	TRS1722			TRS1755			TRS1766			
		TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V _f	Forward voltage	$I_f = 20 \text{ mA}$		2.2	3		2.3	3		2.7	4	V
l _r	Reverse leakage	$V_r = 5 V$			10			10			10	μA
Po	Radiant flux	l _f = 5 mA		14			5			300		μW
λ	Wavelength	l _f = 5 mA		630			567			468		nm
BW	Bandwidth	l _f = 5 mA		40			26			26		nm



TAOS034 - NOVEMBER 2002

Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C, R_L = 10 k Ω (unless otherwise noted) (continued)

		TEAT CONDITIONS	Т	RS172	2	Т	RS175	5	TRS1766			
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V_{D}	Dark voltage	$E_e = 0$	0		20	0		20	0		20	mV
v	Maximum output voltage	No Load		4.49			4.49			4.49		V
V _{OM}	swing	$R_L = 10 \ k\Omega$	4	4.2		4	4.2		4	4.2		V
α_{VD}	Temperature coefficient of dark voltage (V _D)	$T_A = 0^{\circ}C$ to $70^{\circ}C$		-15			-15			-15		μV/°C
	Irradiance responsivity	$\lambda_p = 470 \text{ nm},$ see Notes 4 and 7		20			90			300		mV/ (μW/ cm ²)
		$\lambda_p = 524 \text{ nm},$ see Notes 5 and 7		35			300			130		
R _e		λ_p =565 nm, see Notes 7 and 8		90			300			22		
		$\lambda_p = 635 \text{ nm},$ see Notes 6 and 7		460			35			13		
	Illuminance responsivity	$\lambda_p = 470 \text{ nm},$ see Notes 4 and 7		0.12			0.47			1.57		
		$\lambda_p = 524 \text{ nm},$ see Notes 5 and 7		0.027			0.24			0.10		V/Ix
R_V		$\lambda_p = 565 \text{ nm},$ see Notes 7 and 8		0.06			0.20			0.015		
		$\lambda_p = 635 \text{ nm},$ see Notes 6 and 7		1.21			0.093			0.033		
PSRR	Power supply rejection	f _{ac} = 100 Hz, see Note 10		55			55			55		٩D
	ratio	f _{ac} = 1 kHz, see Note 10		35			35			35		dB
I _{DD}	Supply current	$V_0 = 2 V$ (typical)		1.9	3.5		1.9	3.5		1.9	3.5	mA

Detector (see Notes 2 and 3)

NOTES: 2. Measured with $R_L = 10 \text{ k}\Omega$ between output and ground.

- 3. Optical measurements are made using small-angle incident radiation from a light-emitting diode (LED) optical source.
- 4. The input irradiance is supplied by an InGaN light-emitting diode with the following characteristics: peak wavelength λ_p = 470 nm, spectral halfwidth $\Delta\lambda^{1/2}$ = 35 nm, luminous efficacy = 75 lm/W.
- 5. The input irradiance is supplied by an InGaN light-emitting diode with the following characteristics: peak wavelength λ_p = 524 nm, spectral halfwidth $\Delta\lambda^{1/2}$ = 47 nm, luminous efficacy = 520 lm/W.
- 6. The input irradiance is supplied by an AIInGaP light-emitting diode with the following characteristics: peak wavelength λ_p = 635 nm, spectral halfwidth $\Delta\lambda^{1/2}$ = 17 nm, luminous efficacy = 150 lm/W.
- 7. Responsivity is characterized over the range V_O = 0.1 V to 4.5 V. The best-fit straight line of Output Voltage V_O versus Irradiance E_e over this range will typically have a positive extrapolated V_O value for $E_e = 0$.
- 8. The input irradiance is supplied by a GaP light-emitting diode with the following characteristics: peak wavelength λ_p = 565 nm, spectral halfwidth $\Delta \lambda^{1/2}$ = 28 nm, luminous efficacy = 595 lm/W.
- Illuminance responsivity R_V is calculated from the irradiance responsivity by using the LED luminous efficacy values stated in Notes 4, 5, 6, and 8, and using 1 $lx = 1 lm/m^2$.
- 10. Power supply rejection ratio PSRR is defined as 20 log ($\Delta V_{DD}(f)/\Delta V_O(f)$) with $V_{DD}(f = 0) = 5$ V and $V_O(f = 0) = 2$ V.



TAOS034 – NOVEMBER 2002

Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C, R_L = 10 k Ω (unless otherwise noted) (continued)

Coupled (see Note 2)

PARAMETER			TRS1722			TRS1755			Т			
		TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
١ _F	LED forward current	V _O = 2 V, d = 1 mm (Note 11)	0.5	2.1	4	2	5	8	0.1	0.4	1.75	mA
	Output voltage	I _f = 2.5 mA, d = 1 mm (Note 11)		2.4								
Vo		I _f = 5 mA, d = 1 mm (Note 11)					2					V
		I _f = 0.25 mA, d = 1 mm (Note 11)								1.3		
V _{ox}	Crosstalk	I _f = 5 mA, no surface (see Note 12)	0	80	300	0	30	200				
		I _f = 1 mA, no surface (see Note 12)							0	130	500	mV

NOTES: 11. Measured using Eastman Kodak neutral white test card having 90% diffuse reflectance located a distance from the front surface of the reflective sensors. Reference: Eastman Kodak catalog number #1257795.

12. Crosstalk is the output voltage measured with the indicated current on the LED and with no reflecting surface. Ambient light is excluded with a black box approximately 20 cm in each dimension.

Switching Characteristics at V_{DD} = 5 V, T_A = 25°C, R_L = 10 k Ω (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tr	Output pulse rise time, 10% to 90% of final value	See Note 13 and Figure 1		160	250	μs
t _f	Output pulse fall time, 10% to 90% of final value	See Note 13 and Figure 1		150	250	μs
t _s	Output settling time to 1% of final value	See Note 13 and Figure 1		330		μs
	Integrated noise voltage	$f = dc to 1 kHz$ $E_e = 0$		200		μVrms
		f = 10 Hz E _e = 0		6		
Vn	Output noise voltage, rms	$f = 100 \text{ Hz}$ $E_e = 0$		6		μV/√ Hz rms
		$f = 1 \text{ kHz}$ $E_e = 0$		7		

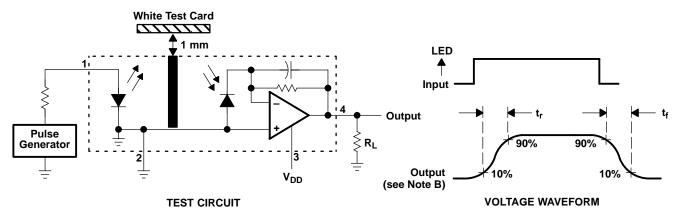
NOTE 13: Switching characteristics apply over the range V_{O} = 0.1 V to 4.5 V.

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PARAMETER MEASUREMENT INFORMATION

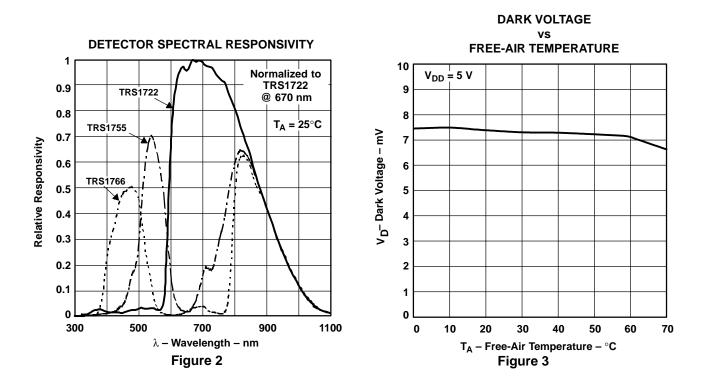


NOTES: A. The input irradiance is supplied by pulsing the LED with a white test card positioned 1 mm from the face of the device.

- B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_r < 100$ ns, $Z_i \ge 1$ M Ω , $C_i \le 20$ pF.
 - C. The pulse generator output drive is adjusted until the sensor output voltage reaches 2 volts.

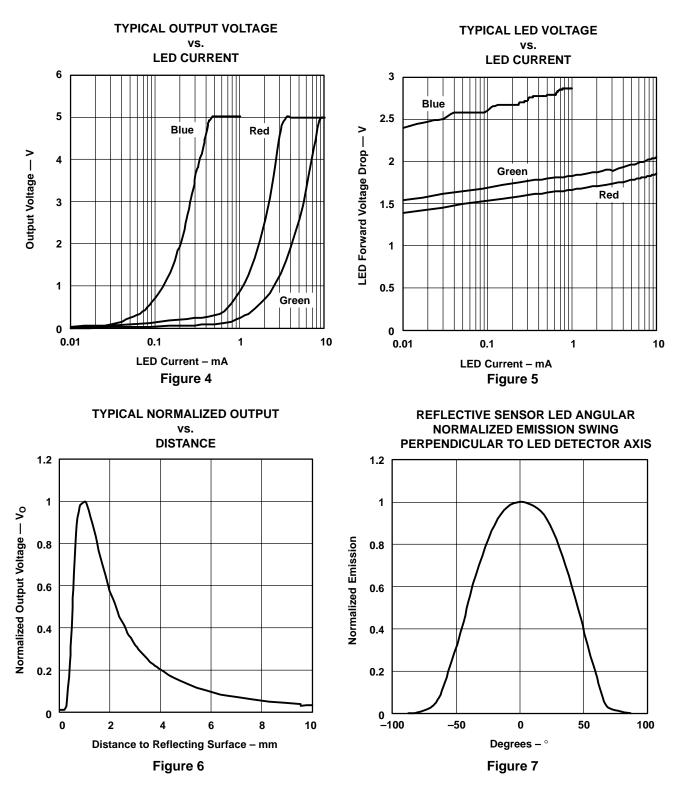
Figure 1. Switching Times

TYPICAL CHARACTERISTICS





TYPICAL CHARACTERISTICS

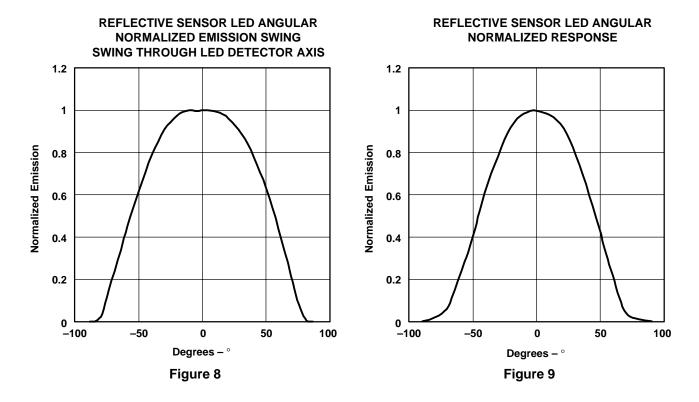




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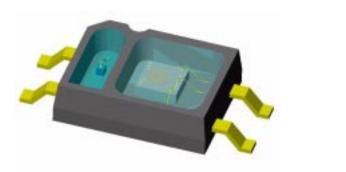
TYPICAL CHARACTERISTICS





TAOS034 - NOVEMBER 2002

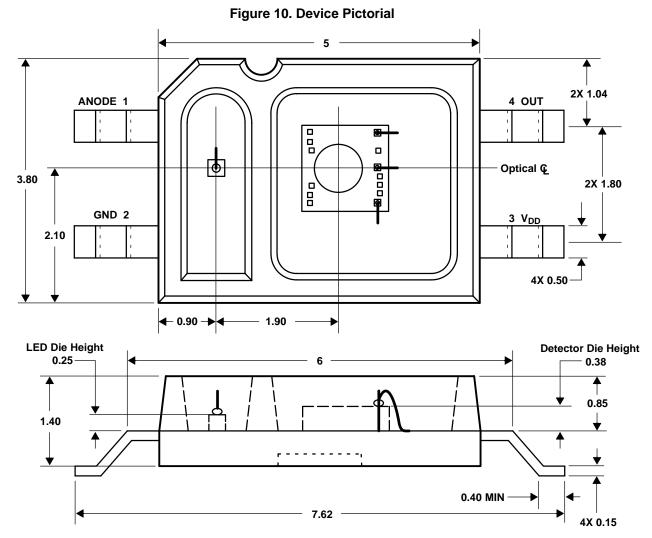
MECHANICAL DATA



Тор



Bottom



NOTES: A. All linear dimensions are in millimeters.

B. Tolerances: die placement: \pm 0.2, plastic package: \pm 0.4, leads: \pm 0.8.

C. This drawing is subject to change without notice.

Figure 11. Package Configuration

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